

## **DECLARATION**

Ø	ORIGINAL
	CONTINUATION
	DIVISIONAL

As a below named inventor. I declare that the information given herein is true, that I believe that I am the original, first and sole inventor if only one name is listed at 1 below, or a joint inventor if plural inventors are named below at 1-4, of the invention entitled: (F.1.

SAPPHIRE MONOCRYSTAL, SEMICONDUCTOR LASER DIODE USING THE SAME FOR SUBSTRATE, AND METHOD FOR MANUFACTURING THE SAME

Ø	the attached specification or			
. 🗆	the specification in application Serial No	filed	🗆 as amended on	

and for which a patent is sought, and that my residence, post office address and citizenship are as stated below next to my name. Accrowledge my duty to disclose information which is material to the examination of this application in accordance with Title 37, Code of Federal Regulations §1.56(a).

hereby state that I have reviewed and understand the contents of the above identified specification, including the claims, as amended by any amendment

referred to above. I hereby claim foreign priority benefits under Title 35, United States Code, §119 of any foreign application(s) for patent or inventor's certificate listed below and have also identified below any foreign application for patent or inventor's certificate having a filing date before that of the application on which priority is claimed:

COUNTRY	APPLICATION NUMBER	DATE OF FILING Month Day Year	PRIORITY CLAIMED UNDER 35 U.S.C. 119	
Japan	8-43862	2 29 1996	YES X_ NO	
Japan	8-43863	2 29 1996	YES <b>x</b> NO	

I hereby claim the benefit under Title 35, United States Code, §120 of any United States application(s) listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of Title 35, United States Code §112, I acknowledge the duty to disclose material information as defined in Title 37, Code of Federal Regulations, §1.56(a) which occurred between the filing date of the prior application and the national or PCT international filing date of this application:

(Application Serial No.)

(Filing Date)

(Status)

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(300)28222800x 202) 223-5700

Residence: CITY STATE or COUNTRY MIDDLE NAME FIRST NAME LAST NAME Name of Gamo-que Kinoshita <u>Hiroyuki</u> C/o Kyocera Corporation, Shiga Factory CITIZENSHIP Post Office Address Gamo-gun, Shiga-prefecture, Japan Gamo-cho 10-1, STATE or COUNTRY
Japan FIRST NAME Motohiro Residence: CITY MIDDLE NAME LAST NAME Name of <u>Gamo-gun</u> Umehara 2 Inventor c/o Kyocera Corporation, Shiga Factory Post Office Address 10-1, Kawai, Gamo-cho, Gamo-gun, Shiga-prefecture, Japan Japan Residence: CITY STATE or COUNTRY MIDDLE NAME LAST NAME FIRST NAME Name of 3 Inventor CITIZENSHIP Post Office Address STATE or COUNTRY MIDDLE NAME Residence: CITY FIRST NAME Name of LAST NAME 4 Inventor CITIZENSHIP Post Office Address

I further declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code, and that such willful false statements may jeopardize the validity of the application or any patent issuing thereon.

SIGNATURE OF INVENTOR 1 Hiroyuki Kinoshita  Hiroyuki Kinoshita.	SIGNATURE OF INVENTOR 2 Motohiro Umehara  Motohiro Umehara		
DATE: February 19, 1997	DATE: February 19, 1997		
SIGNATURE OF INVENTOR 3	SIGNATURE OF INVENTOR 4		
DATE:	DATE:		